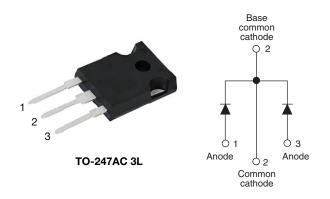
High Performance Schottky Rectifier, 2 x 15 A



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PRIMARY CHARACTERISTICS							
I _{F(AV)} 2 x 15 A							
V _R	35 V, 45 V						
V _F at I _F	See Electrical table						
I _{RM} max.	100 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	10 mJ						
Package	TO-247AC 3L						
Circuit configuration	Common cathode						

FEATURES

- 150 °C T_J operation
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- COMPLIANT HALOGEN
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-MBR30..WT... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES							
I _{F(AV)}	Rectangular waveform (per device)	30	^						
I _{FRM}	$T_{\rm C}$ = 125 °C (per leg)	30	A						
V _{RRM}		35/45	V						
I _{FSM}	t _p = 5 μs sine	1020	А						
V _F	20 A _{pk} , T _J = 125 °C	6	V						
TJ	Range	-65 to +150	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBR3035WT-N3	VS-MBR3045WT-N3	UNITS				
Maximum DC reverse voltage	V _R	35	45	V				
Maximum working peak reverse voltage	V _{RWM}	33	45	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CON	TEST CONDITIONS		UNITS				
Maximum average per leg				15					
forward current per device	I _{F(AV)}	$T_{C} = 125 \text{ °C}, \text{ rated } V_{R}$		30					
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 k	Hz T _C = 125 °C	30	1				
Non-repetitive peak surge current	I _{FSM}	5 μ s sine or 3 μ s rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1020	A				
		Surge applied at rated load conditions half wave, single phase, 60 Hz		200					
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 5 mH		10	mJ				
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2	А				
Peak repetitive reverse surge current	I _{RRM}	2.0 µs 1.0 kHz	2.0						

Revision: 09-Apr-18

Document Number: 96483

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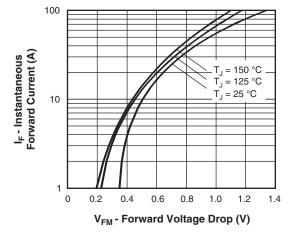
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		30 A	T _J = 25 °C	0.76				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	T _ 105 °C	0.60	V			
		30 A	T _J = 125 °C	0.72				
	1 (1)	T _J = 25 °C	Pated DC valtage	1.0	mA			
Maximum instantaneous reverse current	I _{RM} (1)	T _J = 125 °C	Rated DC voltage	100				
Threshold voltage	V _{F(TO)}	T T maximum		0.29	V			
Forward slope resistance	r _T	$I_{\rm J} = I_{\rm J}$ maximum	$T_J = T_J maximum$		mΩ			
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	800	pF				
Typical series inductance	L _S	Measured from top of tern	7.5	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

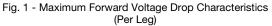
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction temperature range	TJ		-65 to 150	°C					
Maximum storage temperature range	T _{Stg}		-65 to 175						
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.40	°C/W					
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.24	C/ W					
Approximate weight			6	g					
Approximate weight			0.21	oz.					
Mounting torque minimum	1		6 (5)	kgf · cm					
maximur	n		12 (10)	(lbf · in)					
Marking device		Case style TO 247AC 21	MBR3	035WT					
Marking device		Case style TO-247AC 3L	MBR3	045WT					







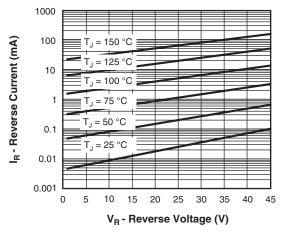


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

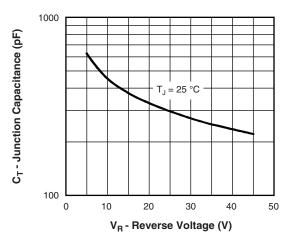


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

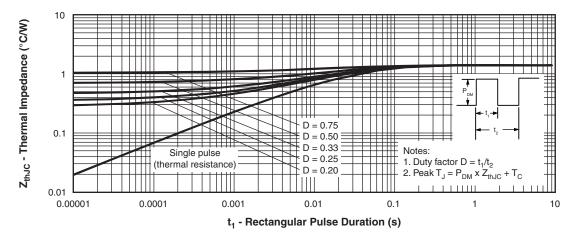


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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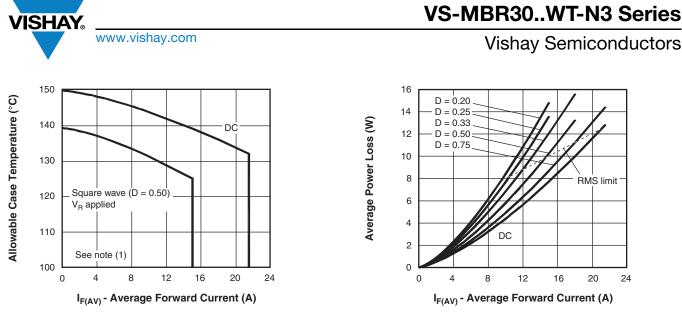
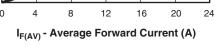


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)



RMS limit

Fig. 6 - Forward Power Loss Characteristics (Per Leg)

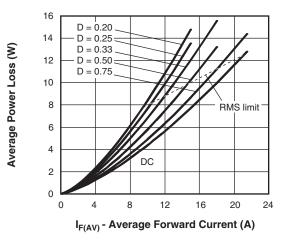
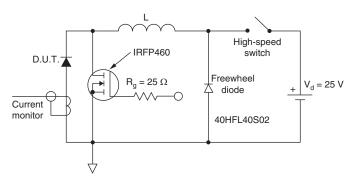


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)





Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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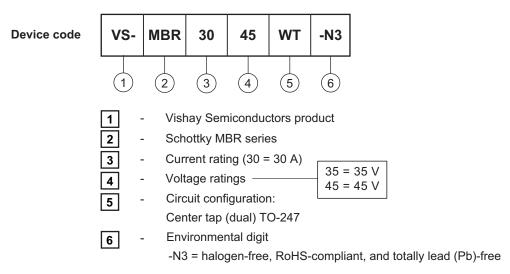
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VS-MBR30..WT-N3 Series

Vishay Semiconductors

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MBR3035WT-N3	25	500	Antistatic plastic tube						
VS-MBR3045WT-N3	25	500	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?96138						
Part marking information	www.vishay.com/doc?95007					



TO-247AC 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØΡ	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	5.51	BSC	0.217	' BSC	
D1	13.08	-	0.515	-	4							

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension Q

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